

Notice of References Cited		Application/Control No.	Applicant(s)/Patent Under Reexamination	
		10/787,133	KAJIYAMA, TAKESHI	
		Examiner	Art Unit	Page 1 of 1
		Evan Pert	2826	

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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*	B	US-6,436,770 B1	08-2002	Leung et al.	438/268
*	C	US-5,475,240 A	12-1995	Sakamoto, Osamu	257/67
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	M	US-			

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NON-PATENT DOCUMENTS

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	V	Inoh et al., "FBC (Floating Body Cell) for Embedded DRAM on SOI, 2003 Symposium on VLSI Technology Digest of technical Papers, pages 63-64.
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.